BCR25KM-12LB

Triac

Medium Power Use

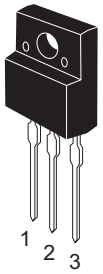
REJ03G1676-0100
Rev.1.00
Jun 05, 2008

Features

- $I_{T\,(RMS)}$: 25 A
- V_{DRM}: 600 V
- I_{FGTI}, I_{RGTI}, I_{RGTIII}: 50 mA
- V_{iso}: 2000 V
- Insulated Type
- Planar Type

Outline

RENESAS Package code: PRSS0003AB-A
(Package name: TO-220FN)



1. T_1 Terminal
2. T_2 Terminal
3. Gate Terminal

Applications

Contactless AC switch, electric heater control, light dimmer, on/off and speed control of small induction motor, on/off control of copier lamp

Maximum Ratings

Parameter	Symbol	Voltage class	Unit
		12	
Repetitive peak off-state voltage Note1	V_{DRM}	600	V
Non-repetitive peak off-state voltage Note1	V_{DSM}	720	V

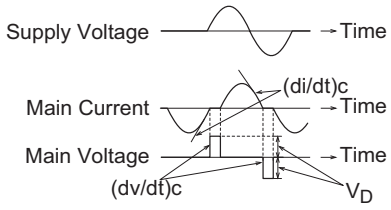
Notes: 1. Gate open.

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	$I_{T\ (RMS)}$	25	A	Commercial frequency, sine full wave 360° conduction, Tc = 62°C
Surge on-state current	I_{TSM}	250	A	50 Hz sinewave 1 full cycle, peak value, non-repetitive
I^2t for fusion	I^2t	313	A^2s	Value corresponding to 1 cycle of half wave 50Hz, surge on-state current
Peak gate power dissipation	P_{GM}	5	W	
Average gate power dissipation	$P_{G\ (AV)}$	0.5	W	
Peak gate voltage	V_{GM}	10	V	
Peak gate current	I_{GM}	2	A	
Junction Temperature	Tj	–40 to +150	°C	
Storage temperature	Tstg	–40 to +150	°C	
Mass	—	2.0	g	Typical value
Isolation voltage	V_{iso}	2000	V	Ta = 25°C, AC 1 minute, T_1 • T_2 • G terminal to case

Electrical Characteristics

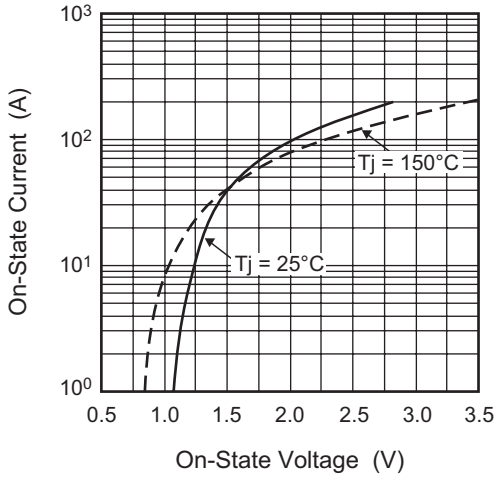
Parameter		Symbol	Min.	Typ.	Max.	Unit	Test conditions
Repetitive peak off-state current		I_{DRM}	—	—	3.0/5.0	mA	Tj = 125/150°C, V_{DRM} applied
On-state voltage		V_{TM}	—	—	1.5	V	Tc = 25°C, I_{TM} = 40 A, instantaneous measurement
Gate trigger voltage[Note2]	I	V_{FGTI}	—	—	2.0	V	Tj = 25°C, V_D = 6 V, R_L = 6 Ω, R_G = 330 Ω
	II	V_{RGTI}	—	—	2.0	V	
	III	V_{RGTIII}	—	—	2.0	V	
Gate trigger curent[Note2]	I	I_{FGTI}	—	—	50	mA	Tj = 25°C, V_D = 6 V, R_L = 6 Ω, R_G = 330 Ω
	II	I_{RGTI}	—	—	50	mA	
	III	I_{RGTIII}	—	—	50	mA	
Gate non-trigger voltage		V_{GD}	0.2/0.1	—	—	V	Tj = 125/150°C, V_D = 1/2 V_{DRM}
Thermal resistance		$R_{th\ (j-c)}$	—	—	2.8	°C/W	Junction to case[Note3]
Critical-rate of rise of off-state commutation voltage[Note4]		(dv/dt)c	10/1	—	—	V/µs	Tj = 125/150°C

Notes: 2. Measurement using the gate trigger characteristics measurement circuit.
3. The contact thermal resistance $R_{th\ (c-f)}$ in case of greasing is 0.5°C/W.
4. Test conditions of the critical-rate of rise of off-state commutation voltage is shown in the table below.

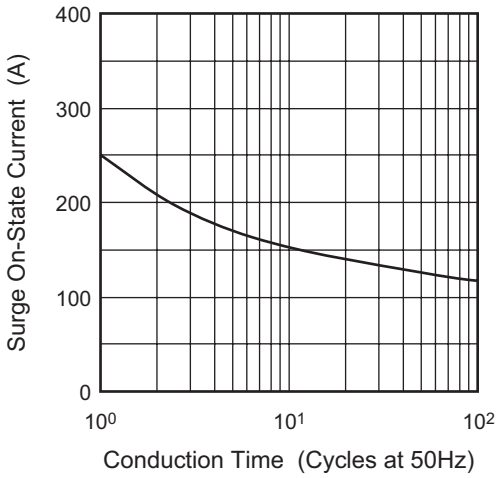
Test conditions	Commutating voltage and current waveforms (inductive load)
1. Junction temperature Tj = 125/150°C 2. Rate of decay of on-state commutating current (di/dt)c = –13 A/ms 3. Peak off-state voltage V_D = 400 V	

Performance Curves

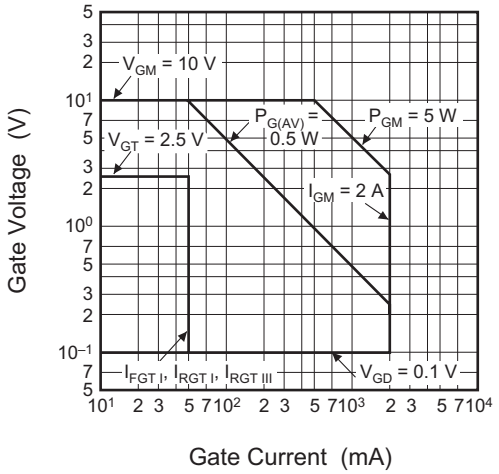
Maximum On-State Characteristics



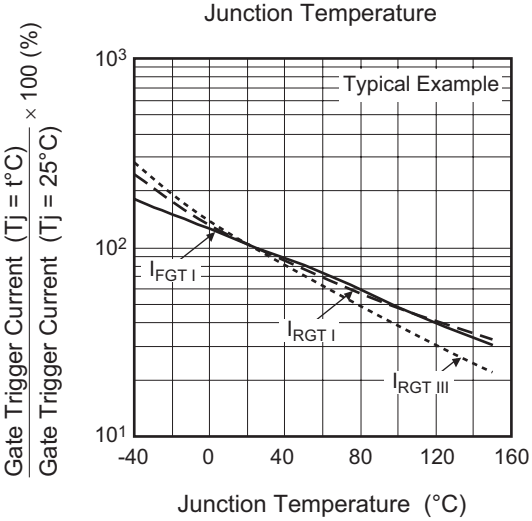
Rated Surge On-State Current



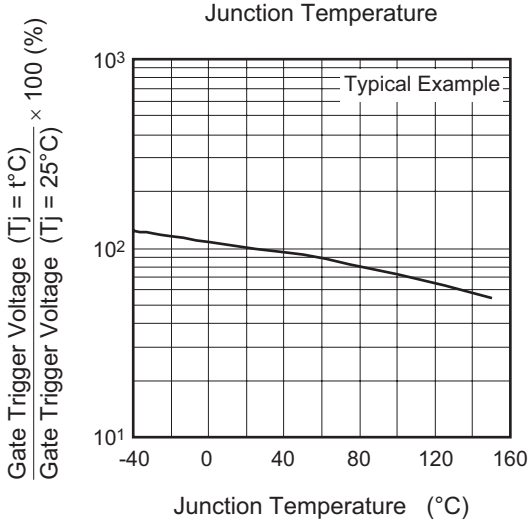
Gate Characteristics (I, II and III)



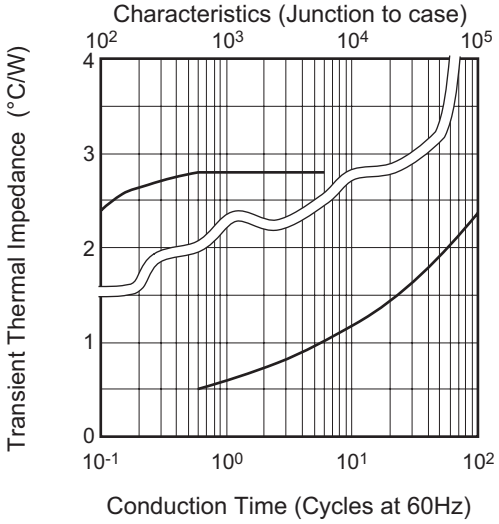
Gate Trigger Current vs. Junction Temperature



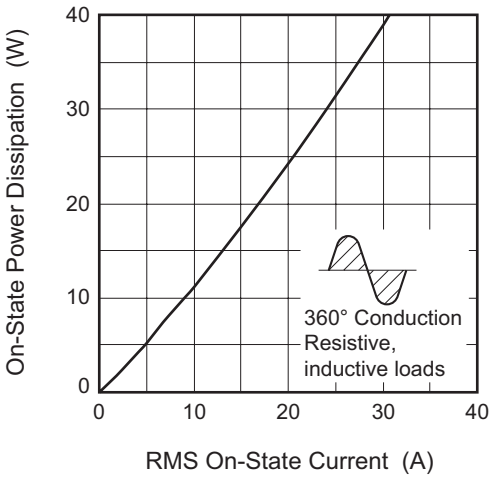
Gate Trigger Voltage vs. Junction Temperature



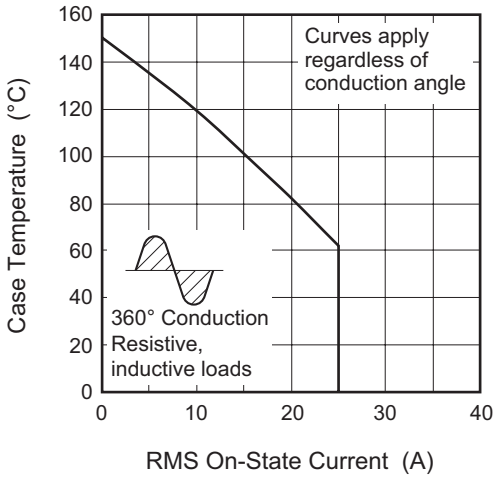
Maximum Transient Thermal Impedance Characteristics (Junction to case)



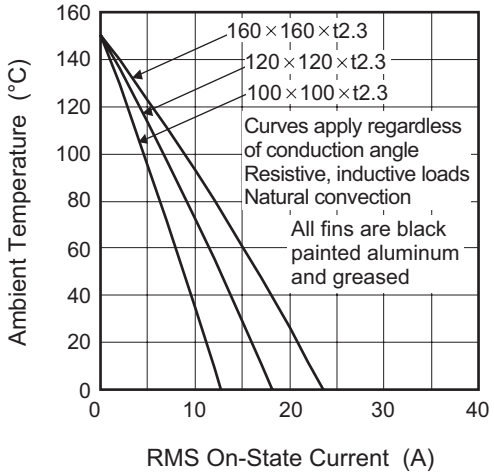
Maximum On-State Power Dissipation



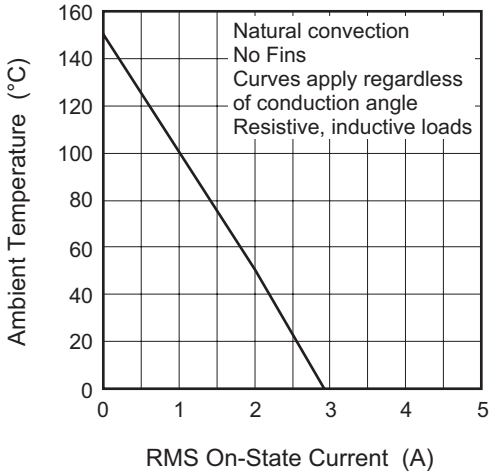
Allowable Case Temperature vs.
RMS On-State Current



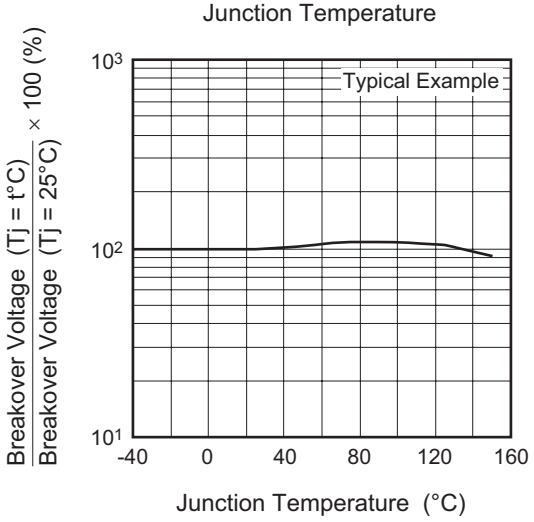
Allowable Ambient Temperature vs.
RMS On-State Current



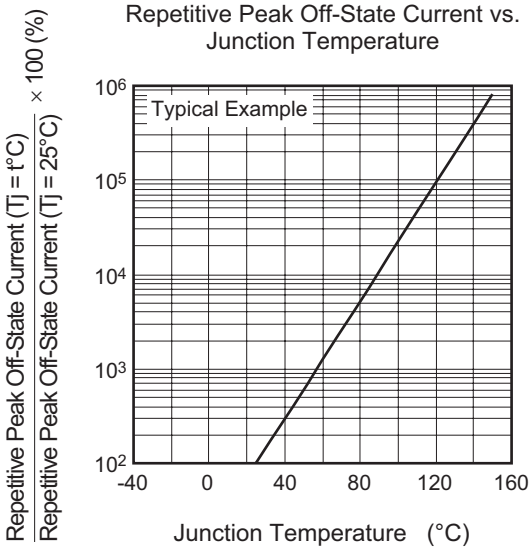
Allowable Ambient Temperature vs.
RMS On-State Current



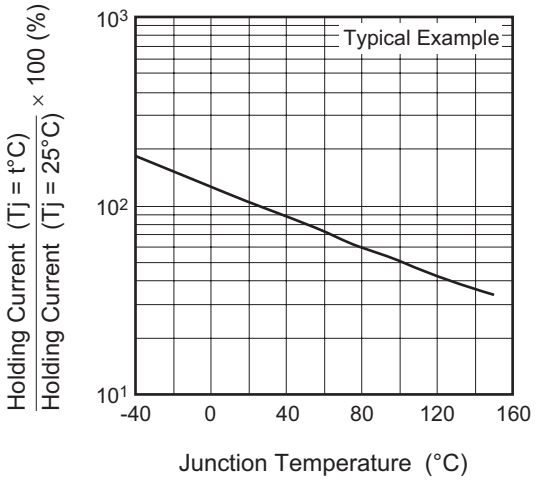
Breakover Voltage vs.
Junction Temperature



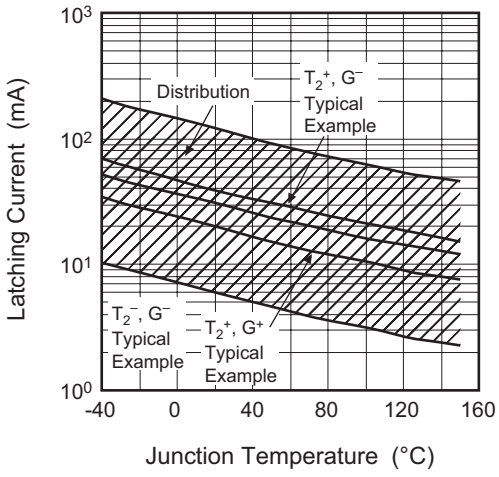
Repetitive Peak Off-State Current vs.
Junction Temperature



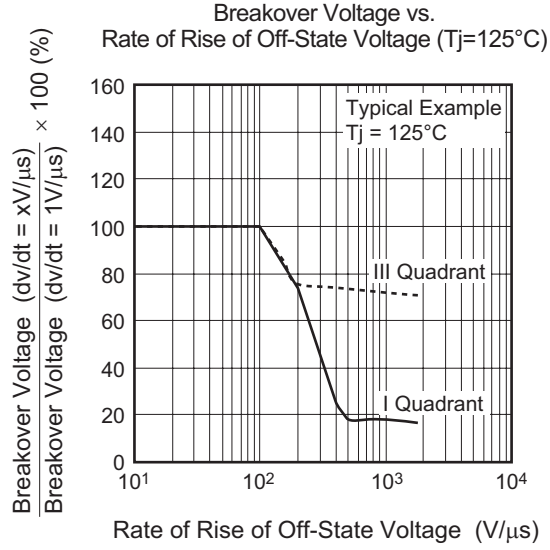
Holding Current vs.
Junction Temperature



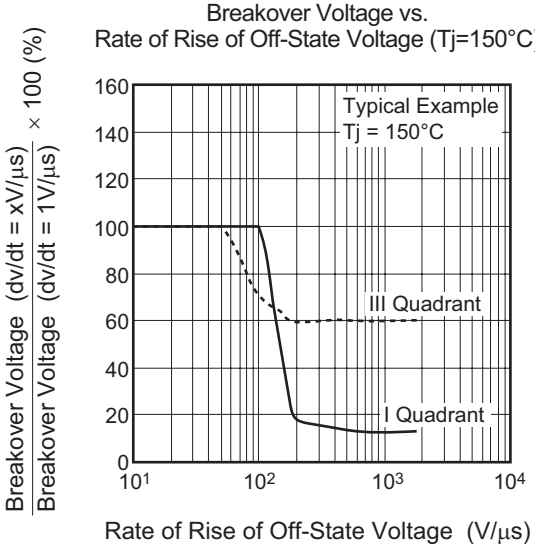
Latching Current vs.
Junction Temperature



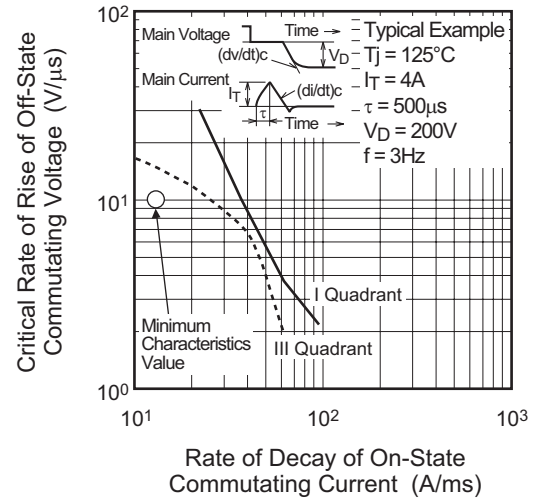
Breakover Voltage vs.
Rate of Rise of Off-State Voltage (Tj=125°C)



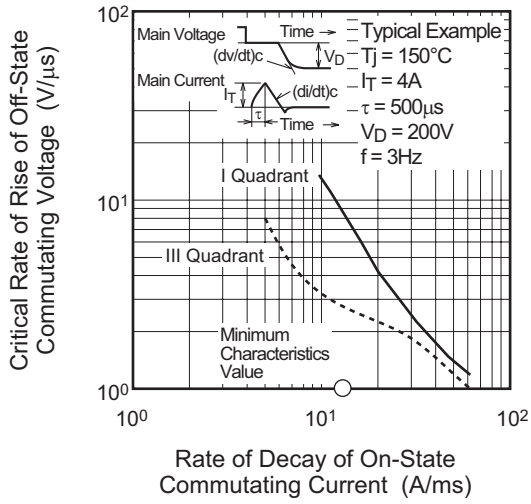
Breakover Voltage vs.
Rate of Rise of Off-State Voltage (Tj=150°C)



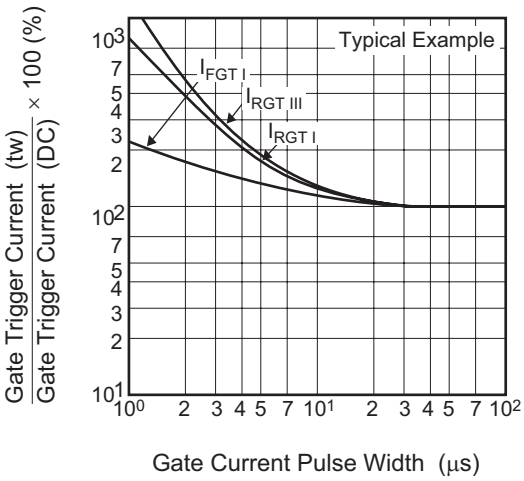
Commutation Characteristics (Tj=125°C)



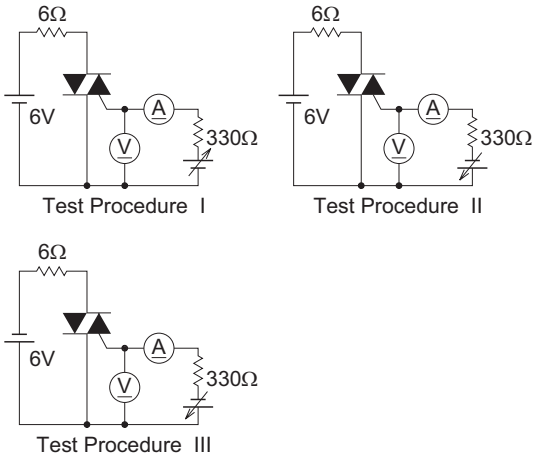
Commutation Characteristics (Tj=150°C)



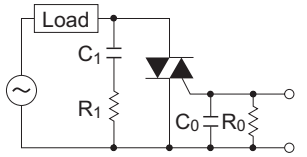
Gate Trigger Current vs.
Gate Current Pulse Width



Gate Trigger Characteristics Test Circuits



Recommended Circuit Values Around The Triac

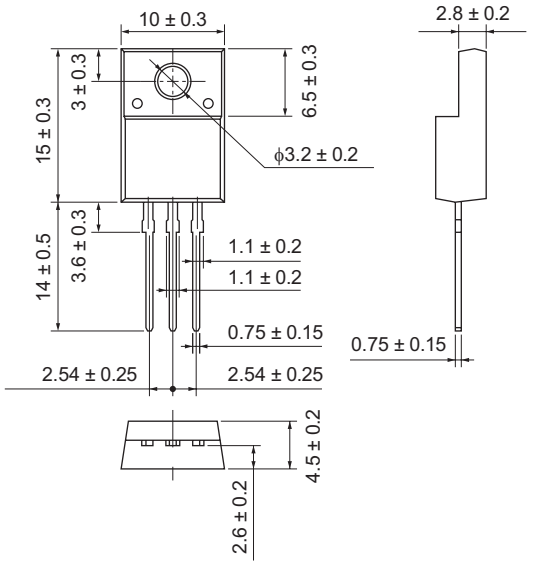


C_1 = 0.1 to 0.47μF C_0 = 0.1μF
R_1 = 47 to 100Ω R_0 = 100Ω

Package Dimensions

Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
TO-220FN	—	PRSS0003AB-A	—	2.0g

Unit: mm



Order Code

Lead form	Standard packing	Quantity	Standard order code	Standard order code example
Straight type	Plastic Magazine (Tube)	50	Type name	BCR25KM-12LB
Lead form	Plastic Magazine (Tube)	50	Type name – Lead forming code	BCR25KM-12LB -A8

Note : Please confirm the specification about the shipping in detail.

Renesas Technology Corp. Sales Strategic Planning Div. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

RENESAS SALES OFFICES

http://www.renesas.com

Refer to "**http://www.renesas.com/en/network**" for the latest and detailed information.

Renesas Technology America, Inc.
450 Holger Way, San Jose, CA 95134-1368, U.S.A
Tel: <1> (408) 382-7500, Fax: <1> (408) 382-7501

Renesas Technology Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology (Shanghai) Co., Ltd.
Unit 204, 205, AZIACenter, No.1233 Lujiazui Ring Rd, Pudong District, Shanghai, China 200120
Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7858/7898

Renesas Technology Hong Kong Ltd.
7th Floor, North Tower, World Finance Centre, Harbour City, Canton Road, Tsimshatsui, Kowloon, Hong Kong
Tel: <852> 2265-6688, Fax: <852> 2377-3473

Renesas Technology Taiwan Co., Ltd.
10th Floor, No.99, Fushing North Road, Taipei, Taiwan
Tel: <886> (2) 2715-2888, Fax: <886> (2) 3518-3399

Renesas Technology Singapore Pte. Ltd.
1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632
Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd.
Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea
Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia
Tel: <603> 7955-9390, Fax: <603> 7955-9510

Colophon .7.2